# **Small Signal MOSFET**

# 20 V, 220 mA, Dual N-Channel, 1.0 mm x 1.0 mm SOT-963 Package

#### **Features**

- Dual N-Channel MOSFET
- Offers a Low R<sub>DS(ON)</sub> Solution in the Ultra Small 1.0 x 1.0 mm Package
- 1.5 V Gate Voltage Rating
- Ultra Thin Profile (< 0.5 mm) Allows It to Fit Easily into Extremely Thin Environments such as Portable Electronics
- This is a Pb-Free Device

#### **Applications**

- General Purpose Interfacing Switch
- Optimized for Power Management in Ultra Portable Equipment
- Analog Switch

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise specified)

Parameter			Symbol	Value	Unit	
Drain-to-Source Voltage			$V_{DSS}$	20	V	
Gate-to-Source Voltage			V <sub>GS</sub>	±8	V	
Continuous Drain	Steady	$T_A = 25^{\circ}C$		220	mA	
Current (Note 1)	State	$T_A = 85^{\circ}C$	$I_{D}$	160		
	t ≤ 5 s	$T_A = 25^{\circ}C$		280		
Power Dissipation	Steady State	T <sub>A</sub> = 25°C	P <sub>D</sub>	125		
(Note 1)					mW	
	t ≤ 5 s			200		
Pulsed Drain Current $t_p = 10 \mu s$			I <sub>DM</sub>	800	mA	
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C	
Source Current (Body Diode) (Note 2)			Is	200	mA	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			$T_L$	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

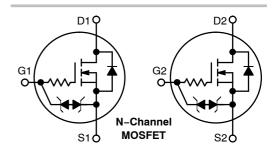
- Surface-mounted on FR4 board using the minimum recommended pad size,
  oz Cu.
- 2. Pulse Test: pulse width  $\leq$ 300  $\mu$ s, duty cycle  $\leq$ 2%

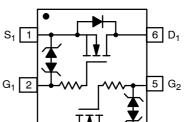


## ON Semiconductor®

#### http://onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> Max
20 V	1.5 Ω @ 4.5 V	
	2.0 Ω @ 2.5 V	0.22 A
	3.0 Ω @ 1.8 V	0.22 A
	4.5 Ω @ 1.5 V	





PINOUT: SOT-963

Top View



 $D_2$  3

SOT-963 CASE 527AD



**MARKING** 

4 S<sub>2</sub>

6 = Specific Device Code

M = Date Code

= Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	D	1000	°C/W
Junction-to-Ambient - t = 5 s (Note 3)	$R_{ hetaJA}$	600	0/ • •

<sup>3.</sup> Surface-mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS				•	•	•	
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 5 V	T <sub>J</sub> = 25°C			50	nA
			T <sub>J</sub> = 85°C			200	
		V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 16 V	T <sub>J</sub> = 25°C			100	nA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> =	±5.0 V			±100	nA
ON CHARACTERISTICS (Note 4)					-		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D = 1$	00 μΑ	0.52		1.0	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>					2.0	mV/°C
Drain-to-Source On Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 100 mA			0.75	1.5	
		V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 50 mA			1.0	2.0	Ω
		V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 20 mA			1.4	3.0	
		V <sub>GS</sub> = 1.5 V, I <sub>D</sub> = 10 mA			1.8	4.5	
		V <sub>GS</sub> = 1.2 V, I <sub>D</sub> = 1.0 mA			2.8		
Forward Transconductance	9FS	V <sub>DS</sub> = 5.0 V, I <sub>D</sub> = 125 mA			0.48		S
Source-Drain Diode Voltage	$V_{SD}$	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 10 mA			0.6	1.0	V
CAPACITANCES					-		
Input Capacitance	C <sub>ISS</sub>				12.5		
Output Capacitance	C <sub>OSS</sub>	f = 1.0 MHz, V <sub>GS</sub> = 0 V V <sub>DS</sub> = 15 V			3.6		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>				2.6		
SWITCHING CHARACTERISTICS, V <sub>GS</sub> = 4.5	<b>V</b> (Note 4)	•		-	-	•	
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS}$ = 4.5 V, $V_{DD}$ = 10 V, $I_{D}$ = 200 mA, $R_{G}$ = 2.0 $\Omega$			16.5		- ns
Rise Time	t <sub>r</sub>				25.5		
Turn-Off Delay Time	t <sub>d(OFF)</sub>				142		
Fall Time	t <sub>f</sub>				80		

 $<sup>{\</sup>bf 4.} \ \ {\bf Switching\ characteristics\ are\ independent\ of\ operating\ junction\ temperatures.}$ 

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTUD3174NZT5G	SOT-963 (Pb-Free)	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### TYPICAL CHARACTERISTICS

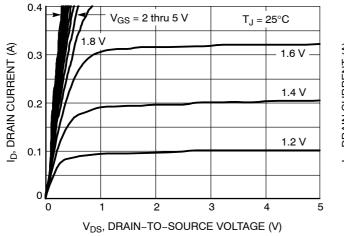


Figure 1. On-Region Characteristics

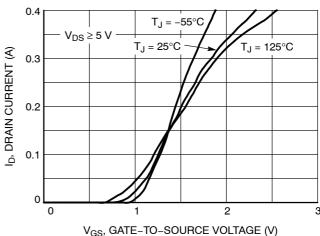


Figure 2. Transfer Characteristics

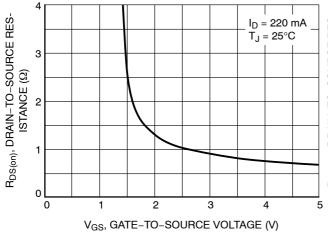


Figure 3. On-Resistance vs. Gate Voltage

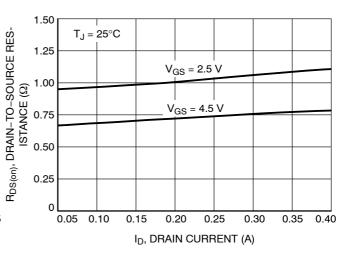


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

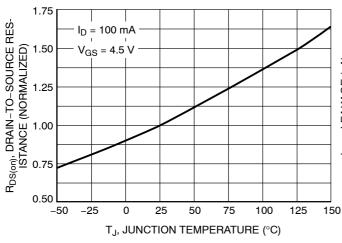


Figure 5. On–Resistance Variation with Temperature

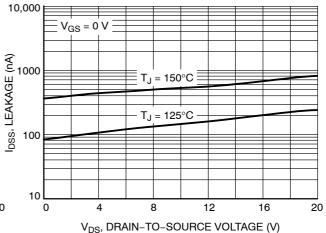
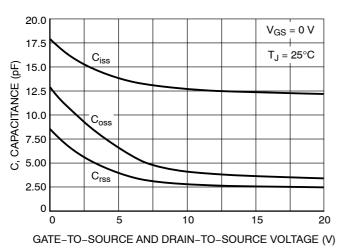


Figure 6. Drain-to-Source Leakage Current vs. Voltage

# **TYPICAL CHARACTERISTICS**



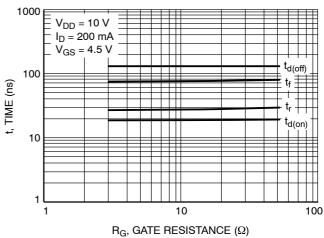


Figure 7. Capacitance Variation

Figure 8. Resistive Switching Time Variation vs. Gate Resistance

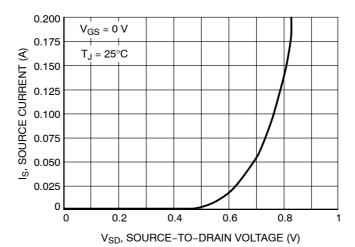
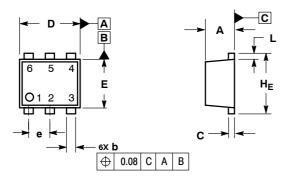


Figure 9. Diode Forward Voltage vs. Current

#### PACKAGE DIMENSIONS

#### SOT-963 CASE 527AD ISSUE D

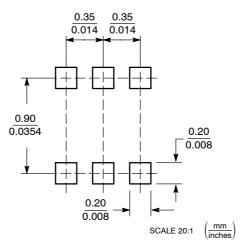


#### NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MON	MAX
Α	0.34	0.37	0.40			
b	0.10	0.15	0.20	0.004	0.006	0.008
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
E	0.75	0.80	0.85	0.03	0.032	0.034
е	0.35 BSC		(	0.014 BS	C	
L	0.05	0.10	0.15	0.002	0.004	0.006
HE	0.95	1.00	1.05	0.037	0.039	0.041

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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